



## MMBT5551 Small Signal NPN Transistor

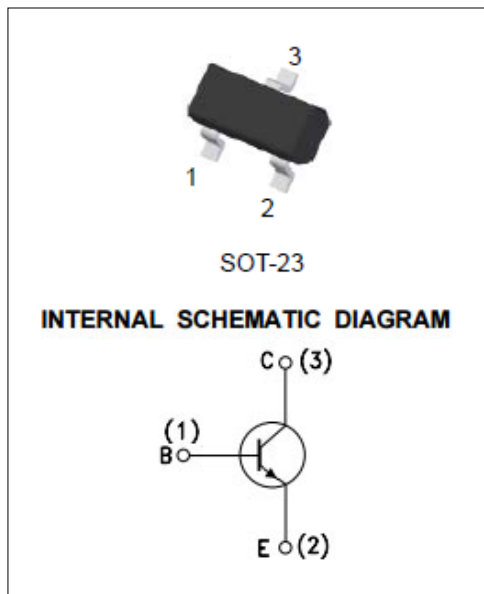
Rev.1.3

### FEATURE:

- Complementary to MMBT5401.
- Power dissipation of 300mW.
- High stability and high reliability.

### MECHANICAL DATA:

- SOT-23 small outline plastic package
- Epoxy UL: 94V-0
- Mounting position: Any
- Marking:G1



### ABSOLUTE MAXIMUM RATINGS( $T_A=25^{\circ}\text{C}$ , unless otherwise specified.)

Parameter	Symbol	Value	Unit
Storage temperature range	$T_{\text{stg}}$	-55 to 150	$^{\circ}\text{C}$
Max. operating junction temperature	$T_j$	150	$^{\circ}\text{C}$
Collector-emitter voltage ( $I_B=0$ )	$V_{\text{CEO}}$	160	V
Collector-base voltage ( $I_E=0$ )	$V_{\text{CBO}}$	180	V
Emitter-base voltage ( $I_C=0$ )	$V_{\text{EBO}}$	6	V
Collector current DC	$I_C$	600	mA
Collector power dissipation	$P_C$	300	mW

**ELECTRICAL CHARACTERISTICS** ( $T_A=25^{\circ}\text{C}$ , unless otherwise specified)

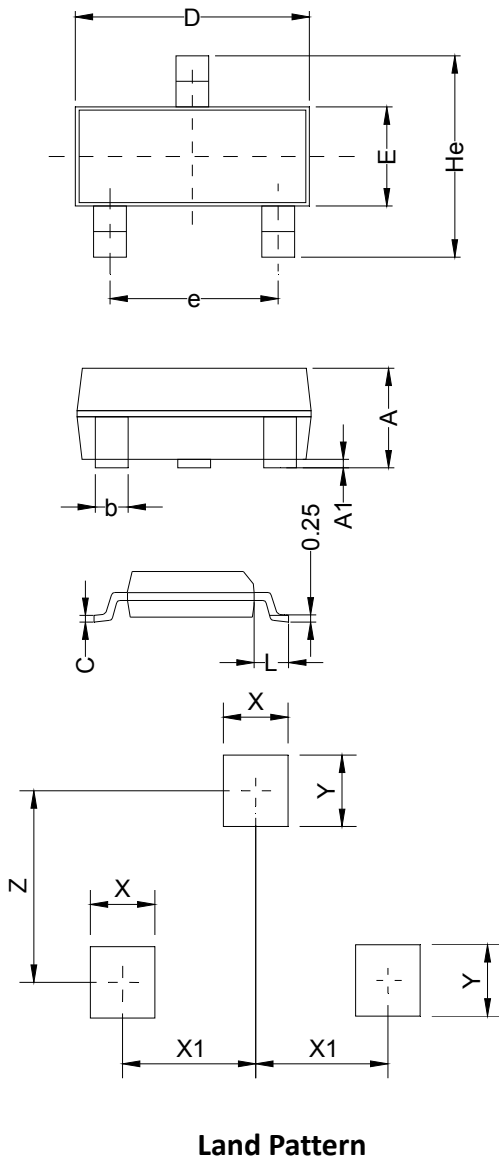
Symbol	Test Condition	Value			Unit
		MIN.	TYP.	MAX.	
$V_{(BR)CBO}$	$I_C=100\mu\text{A}, I_E=0$	180	-	-	V
$V_{(BR)CEO}$	$I_C=1\text{mA}, I_B=0$	160	-	-	V
$V_{(BR)EBO}$	$I_E=10\mu\text{A}, I_C=0$	6	-	-	V
$I_{CBO}$	$V_{CB}=120\text{V}, I_E=0$	-	-	50	nA
$I_{EBO}$	$V_{EB}=4\text{V}, I_C=0$	-	-	50	nA
$h_{FE}^*$	$I_C=1\text{mA}, V_{CE}=5\text{V}$	80	-	-	
	$I_C=10\text{mA}, V_{CE}=5\text{V}$	100	300	-	
	$I_C=50\text{mA}, V_{CE}=5\text{V}$	30	-	-	
$V_{CE(sat)}^*$	$I_C=10\text{mA}, I_B=1\text{mA}$	-	-	0.15	V
	$I_C=50\text{mA}, I_B=5\text{mA}$	-	-	0.20	
$V_{BE(sat)}^*$	$I_C=10\text{mA}, I_B=1\text{mA}$	-	-	1.0	V
	$I_C=50\text{mA}, I_B=5\text{mA}$	-	-	1.0	
$I_{CES}$	$V_{CB}=10\text{V}$	-	-	50	nA
	$V_{CB}=75\text{V}$	-	-	100	
$f_T$	$V_{CE}=10\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	100	-	300	MHz

\* Pulsed: pulse duration = 300 $\mu\text{s}$ , duty cycle  $\leq 2\%$

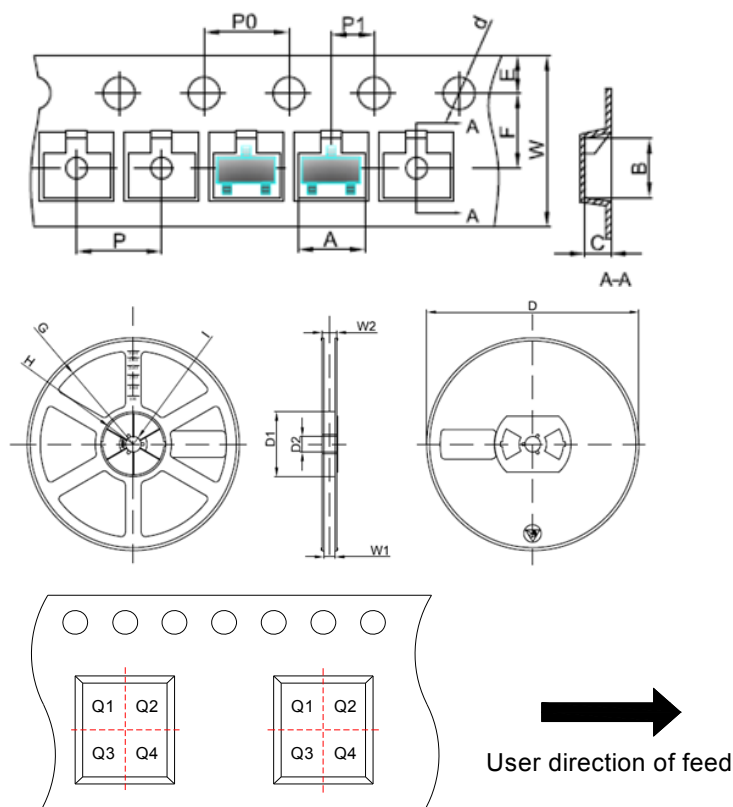
**THERMAL RESISTANCES**

Symbol	Parameter	Value (Max.)	Unit
$R_{th(J-A)}$	junction to ambient	416	$^{\circ}\text{C}/\text{W}$

PACKAGE MECHANICAL DATA



Symbol	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.90	1.063	1.15	0.035	0.042	0.045
A1	0.00	0.075	0.14	0.000	0.003	0.006
b	0.30	0.40	0.50	0.012	0.016	0.020
C	0.07	0.10	0.15	0.003	0.004	0.006
D	2.80	2.90	3.00	0.110	0.114	0.118
e	1.80	1.90	2.00	0.071	0.075	0.079
E	1.20	1.30	1.40	0.047	0.051	0.055
L	0.55REF			0.022REF		
He	2.25	2.40	2.55	0.089	0.094	0.100
X	0.80			0.031		
X1	0.95			0.037		
Y	0.80			0.031		
Z	2.02			0.080		

**TAPE AND REEL SPECIFICATION-SOT-23**


Pin 1 quadrant: Q3

**Packaging Description:**

SOT-23 parts are shipped in tape. The carrier tape is made from a dissipative(carbon filled) polycarbonate resin. The cover tape is a multilayer film(heat activated adhesive in nature)primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000units per 7" or 17.8cm diameter reel. The reels are clear in color and made of polystyrene plastic(anti-static coated).

Symbol	Millimeters	Inches
	Typ.	Typ.
A	3.15	0.124
B	2.77	0.109
C	1.22	0.048
d	Φ1.50	Φ0.059
E	1.75	0.069
F	3.50	0.138
P0	4.00	0.157
P	4.00	0.157
P1	2.00	0.079
W	8.00	0.315
D	Φ178	Φ7.008
D1	54.40	2.142
D2	13.00	0.512
G	R78.00	R3.071
H	R25.60	R1.008
I	R6.50	R0.256
W1	9.50	0.374
W2	12.30	0.484

**ORDERING INFORMATION**

Part Number	Package	Reel Size	Quantity Per Reel
MMBT5551	SOT-23	7 Inch	3,000 pcs

FIG.1: Static characteristic

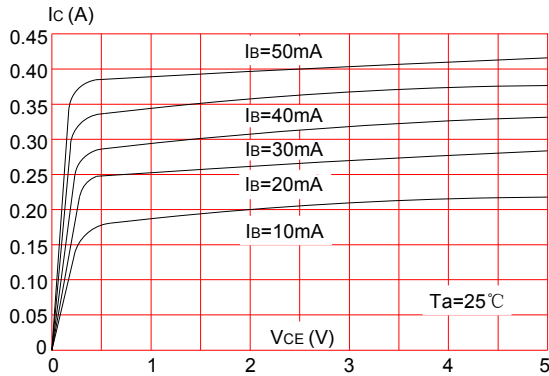


FIG.3: Base current vs. collector emitter saturation voltage

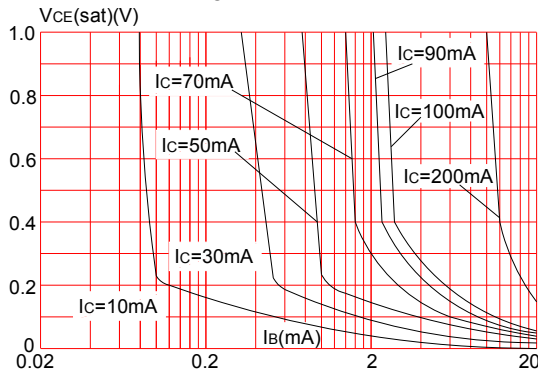


FIG.5: Collector current vs. base emitter saturation voltage

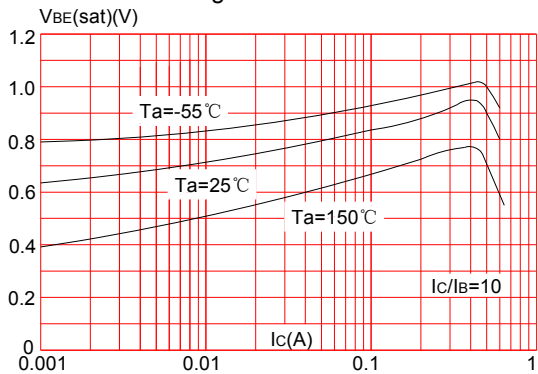


FIG.7: Collector current vs. collector emitter saturation voltage (Ic/Ib=10)

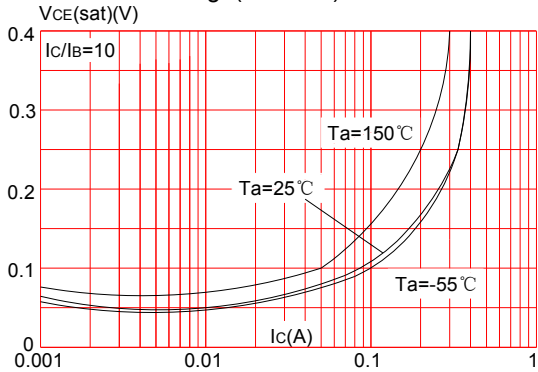


FIG.2: Collector current vs. DC current gain

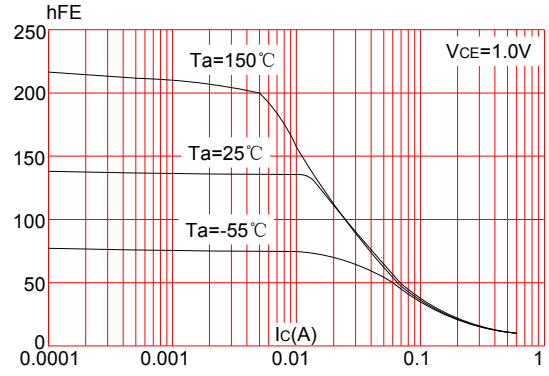


FIG.4: Collector current vs. base emitter voltage (on)

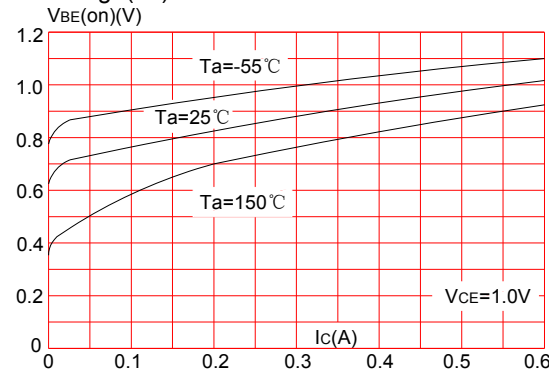


FIG.6: Collector current vs. collector emitter saturation voltage (Ic/Ib=5)

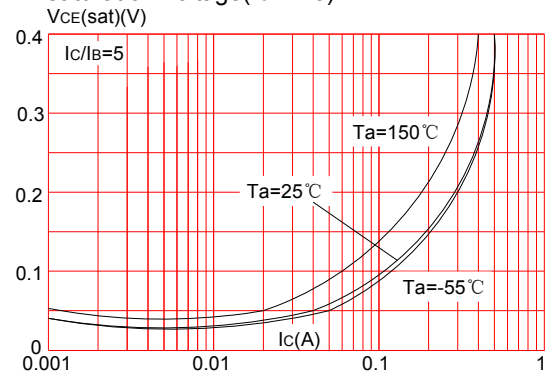


FIG.8: Capacitance characteristic

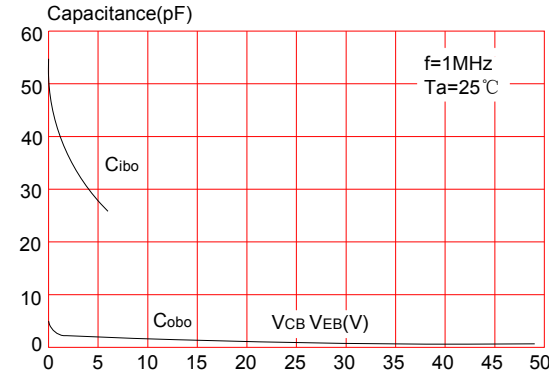
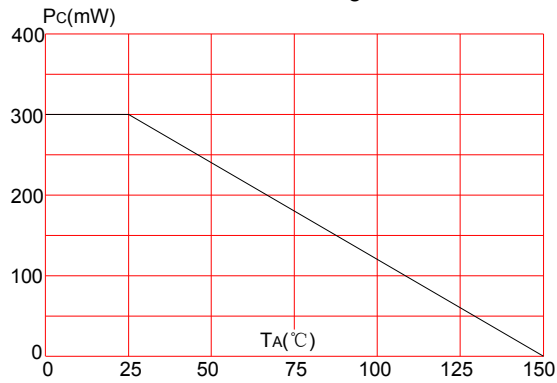


FIG.9: Power derating curve



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